

PM85-F1P1N

1.25/2.5Gbps 850nm VCSEL TO-46 Can Package

Features

- : Multi-mode 850nm VCSEL
- : 1.25 / 2.5 Gbps data rates
- : Low drive current and voltage
- : Flat window Type TO-46 Can Package
- : Back monitor Photo diode
- : Attenuating coating
- : Other configurations available on request

Applications

- : High speed Data Communications
- : Gigabit Ethernet
- : Fiber Channel

Description



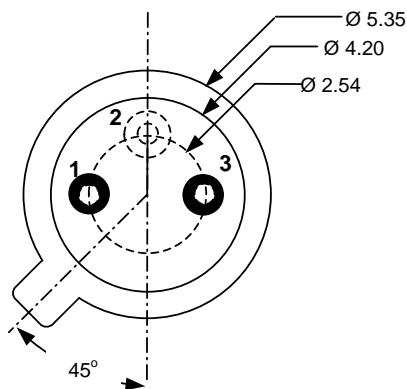
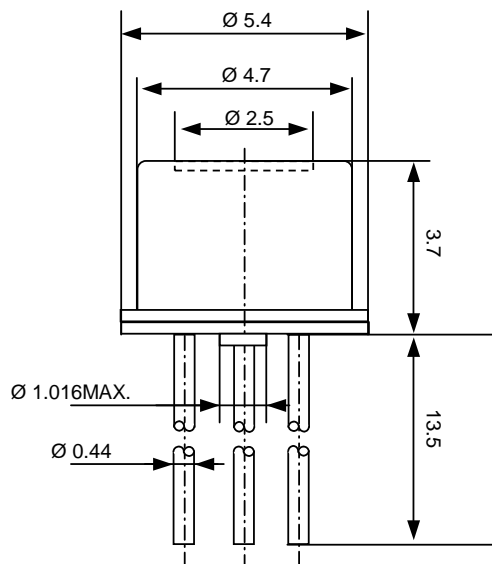
Absolute Maximum Ratings

Parameter	Rating
Storage Temperature	-40 to 100 °C
Operating Temperature	0 to 85 °C
Lead Solder Temperature	260 °C, 10 sec
Continuous Forward Current	12mA
Continuous Reverse Voltage	5V (@10µA)

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Dimensions



Bottom view

PINOUT

Number	Function
1	A _{LD}
2	K _{LD,APD}
3	K _{PD}

Unit:mm

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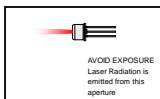
Electro-Optics Characteristics ($T_a=25^\circ\text{C}$ unless otherwise stated)

Parameters	Symbol	Specified			Unit	Test Conditions
		Min.	Typ.	Max.		
Optical Output Power	P_o		0.7		mW	$I_f = 7\text{ mA}$
Threshold Current	I_{th}		1.5	3	mA	CW
I_{th} Temperature Variation	ΔI_{th}		1.5		mA	$T_a=0$ to 85°C
Slope Efficiency	η	0.08	0.12	0.25	W/A	$I_f = 7\text{ mA}$
η Temperature Variation	$\Delta\eta / \Delta T$		-0.5		%/°C	$T_a=0$ to 85°C at 7 mA
Peak Wavelength	λ_p	840	850	860	nm	$I_f = 7\text{ mA}$
λ_p Temperature Coefficient	$\Delta\lambda / \Delta T$		0.06		nm/°C	$T_a=0$ to 85°C at 7 mA
Spectral Bandwidth (RMS)	$\Delta\lambda$			0.85	nm	$I_f = 7\text{ mA}$
Forward Voltage	V_f		1.7	2.2	V	$I_f = 7\text{ mA}$
Breakdown Voltage	V_b		-10		V	
Rise and Fall Times	t_r			130	ps	Prebias Above Threshold, 20%~80%
	t_f			150		
Relative Intensity Noise	RIN		-130	-122		1 GHz BW, $I_f = 7\text{ mA}$
Series Resistance	R_s	20	35	55	Ohm	$I_f = 7\text{ mA}$
R_s Temperature Coefficient	dR_s/dT		-3000		PPM/°C	

Parameters	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Monitor Current	I_{PD}		0.5		mA	$P_o=0.7\text{ mW}$
I_{PD} Temperature Variation	$\Delta I_{PD}/\Delta T$		0.2		%/°C	$P_o=0.7\text{ mW}$
Dark current	I_b			20	nA	$P_o=0\text{ mW}, V_R=3\text{ V}$
PD Reverse Voltage	BV_{RPD}	30	115		V	$P_o=0\text{ mW}, I_R=10\mu\text{ A}$
PD Capacitance	C			100	pF	$V_R=0\text{ V}, \text{Freq}=1\text{ MHz}$
				55		$V_R=3\text{ V}, \text{Freq}=1\text{ MHz}$

Notes

* These specifications are subject to change without notice



NOTICE

The inherent design of this component causes it to be sensitive to electrostatic discharge(ESD). To prevent ESD-induced damage and/or degradation to equipment, take normal ESD precautions when handling this product

DANGER

The VCSEL is a class IIIb laser and should be treated as a potential eye hazard. Due to the size of the component, the applicable warning logotype, aperture label, and certification / identification label cannot be placed on the component itself.

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Characteristics Curves

